

# AN INTRODUCTION TO POLYFET RF DEVICES: COMPANY AND PRODUCTS

# WHO IS POLYFET RF DEVICES?

Founded in 1988, Polyfet RF Devices is a California based, ISO 9001:2015 certified, manufacturer of broadband LDMOS, VDMOS, and GaN power transistors and power modules.

#### PRIVATE CORPORATION

## POLYFET'S FINANCIALS

PROFITABLE EACH YEAR SINCE 1991

OWN OUR BUILDING AND CAPITAL EQUIPMENT

NO LONG-TERM DEBT

#### MANUFACTURING AND TEST EQUIPMENT

West Bond die attach machines

West Bond automatic wire bond machines

Scientific Test DC Test Sets

**RJR Lidding Machines** 

Agilent RF Test Equipment

Werlatone, Innovative Power Products, Insulated Wire (IW), and Aeroflex/Weinschel.

## HOW DOES POLYFET SIZE UP?

#### HAVE 28 EMPLOYEES

7500 (700 SQUARE METERS) SQUARE FOOT FACILITY

ISO9001:2015 AND MIL-PRF-19500 STANDARDS

**AUTOMATED ASSEMBLY EQUIPMENT** 

CURRENT THROUGHPUT CAPABILITY OF OVER 5KPCS/MO (CAN INCREASE BY ADDING 2<sup>ND</sup> SHIFT)

OWN OUR MASKS (IP)

# WHAT DOES POLYFET OFFER TO THE MARKET?

**GaN** transistors

LDMOS transistors

**VDMOS** transistors

Broadband modules

Linear and non-linear models for simulation

2 - 4wk lead times

Application notes

Custom amplifier and module design service

**Technical support** 

Long-Term (20+ years) production support

## GALLIUM NITRIDE TRANSISTORS

GaN on SiC technology (high thermal conductivity)

Usable power/gain up to 3GHz

Output power up to 160W P3dB CW

Operating voltage across 24 - 48VDC

Our GP package shown bottom right

Our GX package shown top right

Full GaN offerings and specifications found in "Product" section of website and shortform catalog





## POLYFET LDMOS DEVICES

Usable power/gain up to 1.5GHz

Output power up to 2kW CW

Operating voltage across 5.0 - 50VDC

Full LDMOS offerings and specifications found in "Product" section of website and shortform catalog









## POLYFET VDMOS DEVICES

Usable power/gain up to 1GHz

Output power up to 400W CW

Operating voltage across 12.5 - 50VDC

Full VDMOS offerings and specifications found in "Product" section of website and shortform catalog









# TECHNICAL BULLETINS (EVALUATION AMPLIFIERS)

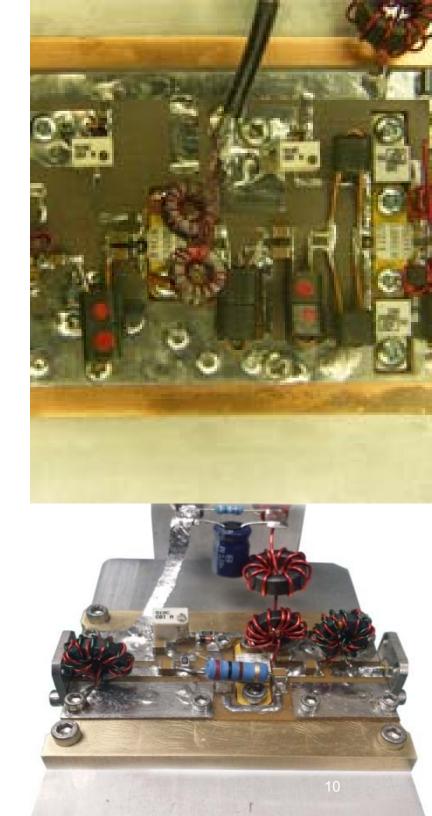
Working amplifiers used to demonstrate the performance of our devices

Free to evaluate

Comes with a complete data package showing performance, PCB layout, and BOM/schematic to copy if desired

Reduces customers' engineering time

Complete amplifier listing in the "Application Notes" section of website



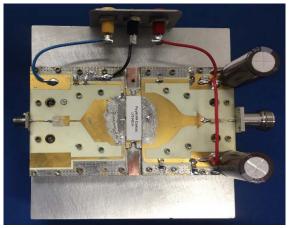
## GAN EVALUATION AMPLIFIERS

- (T) TB243 featuring the GX3442: 1-1000MHz, 70W P3dB, 15dB, 40%, 48VDC
- (M) TB255 featuring the GX3442: 30-512MHz, 100W P3dB, 19dB, 65%, 48VDC
- (B) TB256 featuring the GP2001: 20-3000MHz, 10W P3dB, 10dB, 25%, 28VDC









- (T) TB230A featuring the LB2401: 20-1000MHz, 100W P1dB, 15dB, 40%, 28VDC
- (M) TB263 featuring the LS2641: 30-512MHz, 180W P1dB, 17dB, 55%, 28VDC
- (B) TB277C featuring the LY2542LR: 1.2-1.4GHz, 850W P1dB (300uS, 12%), 14dB, 50%, 50VDC

## LDMOS EVALUATION AMPLIFIERS







- (T) TB224 featuring the SP201: 30-512MHz, 1.0W P1dB, 10dB, 12%, 28VDC
- (M) TB184C featuring the SR401: 2-30MHz, 200W P1dB, 20dB, 50%, 28VDC
- (B) TB252 featuring the SA721→SM724: 118-136MHz, 25W P1dB, 30dB, 40%, 28VDC

## VDMOS EVALUATION AMPLIFIERS

## BROADBAND MODULES

Frequency range of 1.6 - 1260MHz

Output power up to 300W

Operating voltage across 12 - 50VDC

Zin/Zout: 50 ohms

Connection type: Feed-thru pin or

**SMA** 

Full Modules offerings and specifications found in "Product" section of website and shortform catalog









### NEW LDMOS DEVICES

Feature high drain breakdown (min 80VDC) voltage for improved ruggedness for the 28V devices, and higher gain than previous generation.

#### Examples:

LB2401: 100W P1dB, 20-1000MHz, 15dB, 40%, 28VDC

LS2541: 150W P1dB, 30-512MHz, 18db, 50%. 28VDC

LS2641: 180W P1dB, 30-512MHz, 17dB, 55%, 28VDC

LS2541HF: 500WP1dB, 2-30MHz, 26dB, 65%, 50VDC

LY2542LB: 800W P1dB (128uS pulse), 960-1215MHz, 14dB, 45%, 50VDC

LY2542LR: 850W P1dB (300uS pulse), 1.2-1.4GHz, 14dB, 50%, 50VDC

LY2843V: 2kW CW, HF and FM, 20dB, 80%, 50VDC

#### LINEAR AND NON-LINEAR DEVICE MODELS

### S-parameters

Spice, ADS, AWR models

Simulation design files for extracting Zin/Zout

Broadband amplifier design files

All found in the "Design" section of web site

#### APPLICATIONS/ MARKETS FOR OUR PRODUCT

```
520-1610kHz (AM)
```

2-30MHz (HF)

30-88MHz (Military ground communications)

54-88MHz (TV VHF I)

88-108MHz (FM)

118-136MHz (Avionics)

136-174MHz (Commercial ground communications)

160-230MHz (TV VHF III)

30-512MHz (Military: Jammer, Ground/Air communications)

470-700MHz (TV UHF)

1MHz - 1000MHz (ISM, NMR, Medical, Instrumentation or EMC)

1-3GHz (L-band avionics/radar, Public communication, Jammers, Instrumentation)

## TECHNICAL SUPPORT

Polyfet understands the complex nature of matching power MOSFETs. Polyfet offers extensive technical support to their customers.

- Majority of customer base is Military
- 20+ year product life cycles
- Obsolescence is rare, not driven by sales
- Still manufacturing products today that we introduced 30 years ago
- Customers come to Polyfet for replacements for obsolete competitors' devices

Examples of replacements:

#### **Ampleon with Polyfet as follows:**

BLF245 with SA701, BLF245B with SE701, BLF404 with S8222

BLF246 with SM704, BLF246B with SD702, BLF147 with SM401

BLF647 with LR2401, BLF1043 with L2801

#### ST Microelectronics with Polyfet as follows:

LET9120 with LB2301

LET9045C with LX2301

#### Semelab with Polyfet as follows:

D2207UK with LQ2001

D1007UK with SK701

D1008UK with SK702

### DO NOT FEAR OBSOLESCENCE

Q4-2025: Release new line of GaN in SiC discrete transistors. Target specifications are 6GHz, up to 30W, 48VDC, 13dB.

#### ROAD MAP FOR POLYFET

## CONTACT INFORMATION



Address: 1110 Avenida Acaso, Camarillo CA 93012



Phone/Fax: 1-805-484-4210/3393



E-mail: contact@polyfet.com



Website: www.polyfet.com